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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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HAT2093R

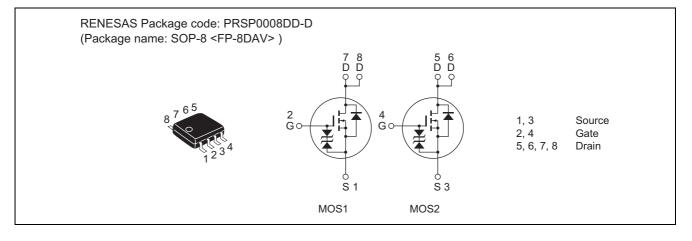
Silicon N Channel Power MOS FET High Speed Power Switching

> REJ03G1185-0300 (Previous: ADE-208-1237A) Rev.3.00 Sep 07, 2005

## Features

- Low on-resistance
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting

## Outline





## **Absolute Maximum Ratings**

		$(Ta = 25^{\circ}C)$
Symbol	Value	Unit
V <sub>DSS</sub>	30	V
V <sub>GSS</sub>	±20	V
ID	9	А
I <sub>D (pulse)</sub> Note 1	72	А
I <sub>DR</sub>	9	А
Pch Note 2	2	W
Pch Note 3	3	W
Tch	150	٥C
Tstg	-55 to +150	٥C
	VDSS VGSS ID ID ID (pulse) Note 1 IDR Pch Note 2 Pch Note 3 Tch	VDSS         30           VGSS         ±20           ID         9           ID (pulse)         72           IDR         9           Pch         2           Pch         3           Tch         150

Notes: 1. PW  $\leq$  10  $\mu s,\,duty\,cycle \leq$  1%

2. 1 Drive operation: When using the glass epoxy board (FR4 40  $\times$  40  $\times$  1.6 mm), PW  $\leq$  10 s

3. 2 Drive operation: When using the glass epoxy board (FR4 40  $\times$  40  $\times$  1.6 mm), PW  $\leq$  10 s

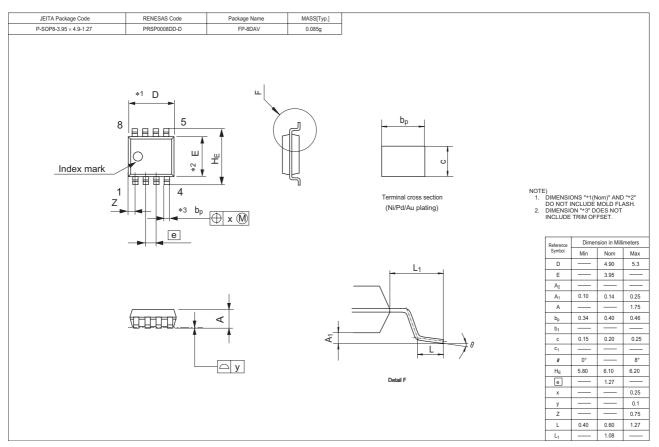
## **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ **Test Conditions** Item Symbol Min Тур Max Unit 30  $I_D = 10 \text{ mA}, V_{GS} = 0$ Drain to source breakdown voltage V (BR) DSS \_\_\_\_ \_ V ±20 V  $I_G=\pm 100~\mu A,~V_{DS}=0$ Gate to source breakdown voltage V (BR) GSS ±10  $V_{GS}=\pm 16~V,~V_{DS}=0$ Gate to source leak current Igss \_ \_ μΑ Zero gate voltage drain current IDSS \_\_\_ \_ 1 μΑ  $V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0$ Gate to source cutoff voltage 1.0 2.5 V  $V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$ V<sub>GS (off)</sub> \_ Static drain to source on state resistance 18  $I_D = 4.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 4}}$ R<sub>DS (on)</sub> \_ 23 mΩ  $I_D = 4.5 \text{ A}, V_{GS} = 4.5 \text{ V}^{Note 4}$ R<sub>DS (on)</sub> 27 39 mΩ  $I_D = 4.5 \text{ A}, V_{DS} = 10 \text{ V}^{Note 4}$ Forward transfer admittance 9 S y<sub>fs</sub> 15 \_ Input capacitance Ciss \_ 750 \_\_\_ pF  $V_{DS} = 10 V$ 200  $V_{GS} = 0$ Output capacitance Coss pF \_ \_\_\_\_ f = 1 MHzReverse transfer capacitance Crss 110 pF  $V_{DD} = 10 V$ Total gate charge Qg 12 nC Gate to source charge Qgs \_ 2.3 \_ nC  $V_{GS} = 10 V$ nC  $I_D = 9 A$ Gate to drain charge Qgd \_ 2.2 \_  $V_{GS} = 10 \text{ V}, I_D = 4.5 \text{ A}$ Turn-on delay time 11 t<sub>d (on)</sub> \_ \_ ns  $V_{DD} \cong 10 \text{ V}$ Rise time 16 tr ns  $R_L = 2.22 \ \Omega$ Turn-off delay time t<sub>d (off)</sub> \_ 40 \_ ns  $Rg = 4.7 \Omega$ Fall time \_ 7 \_ ns tf  $I_F = 9 \text{ A}, V_{GS} = 0^{\text{Note 4}}$ Body-drain diode forward voltage  $V_{\text{DF}}$ 0.85 1.10 V \_  $I_{F} = 9 A, V_{GS} = 0$ Body-drain diode reverse recovery time 50 trr \_ ns  $di_F/dt = 50 A/\mu s$ 

Note: 4. Pulse test



## **Package Dimensions**



## **Ordering Information**

Part Name	Quantity	Shipping Container
HAT2093R-EL-E	2500 pcs	Taping

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